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## BAT42W/BAT43W SURFACE MOUNT SCHOTTKY BARRIER DIODE



#### **Features**

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material —UL Recognition Flammability Classification 94V-O
- Green Products in Compliance with the ROHS Directive
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# **Circuit Diagram**



#### **Mechanical Data**

- Case: SOD-123, Molded Plastic
- Terminals: Plated leads Solderable per MIL-STD-202,

Method 208

Polarity: Cathode BandWeight: 0.01 grams(approx.)

### Maximum Ratings @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	BAT42W/BAT43W	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	30	V
RMS Reverse Voltage	$V_{R(RMS)}$	21	V
Forward Continuous Current	I <sub>FM</sub>	0.2	А
Repetitive Peak Forward Current @t<1.0s	I <sub>FRM</sub>	500	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	4.0	А
Power Dissipation	Pd	500	mW
Typical Thermal Resistance Junction to Ambient	R <sub>eJA</sub>	200	°C/W
Junction Temperature Range	TJ	125	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

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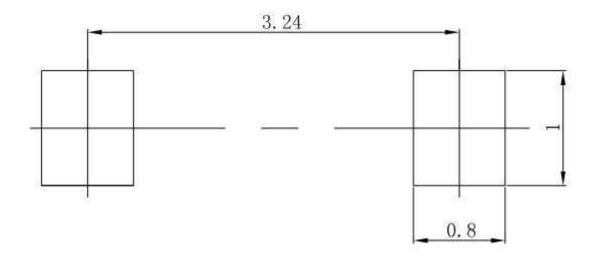




# Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Ch	aracteristic	Symbol	Min	Тур	Max	Units	Test Condition
Reverse Breakdown Vo	oltage	V <sub>(BR)</sub>	30	-	-	V	I <sub>R</sub> =10µA
	All Types	V <sub>F</sub>	-	-	1.0	V	I <sub>F</sub> =200mA
	BAT43W	V <sub>F</sub>	-	-	0.4	V	I <sub>F</sub> =10mA
Forward Voltage		V <sub>F</sub>	-	-	0.65	V	I <sub>F</sub> =50mA
		V <sub>F</sub>	0.26	-	0.33	V	I <sub>F</sub> =2mA
BAT43W		$V_{F}$	-	-	0.45	V	I <sub>F</sub> =15mA
Reverse Leakage Curre	ent	I <sub>R</sub>	-	-	0.5	μA	V <sub>R</sub> =25V
Junction Capacitance		Cj	-	-	10	pF	V <sub>R</sub> =1.0V,f=1.0MHz

# **SOD-123 Suggested Pad Layout**



Note: 1. Controlling dimension: in millimeters.

2. General tolerance:  $\pm 0.05$ mm.

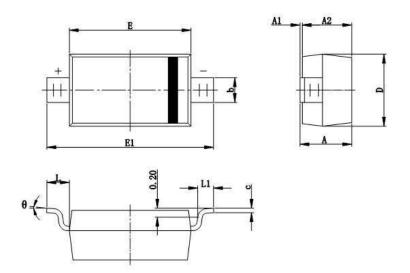
3. The pad layout is for reference purposes only.







### **Mechanical Dimensions SOD-123**



0)/44001	Millin	neters	Inches		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.450	0.650	0.018	0.026	
С	0.080	0.150	0.003	0.006	
D	1.500	1.700	0.059	0.067	
Е	2.600	2.800	0.102	0.110	
E1	3.550	3.850	0.140	0.152	
L	0.500 REF.		0.020 REF.		
L1	0.250	0.450	0.010	0.018	
θ	0°	8°	0°	8°	

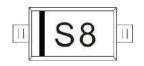
### **Ordering Information**

Device	Package	Shipping
BAT42(43)W	SOD-123	3000pcs / reel
B/(142(40)**	(Pb-Free)	0000000071001

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**

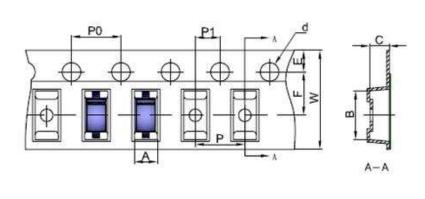




BAT42W

BAT43W

# **Carrier Tape Specification SOD-123**



SYMBOL	Millimeters			
	Min.	Max.		
Α	1.80	1.90		
В	3.89	3.99		
С	1.52	1.62		
d	1.45	1.65		
E	1.65	1.85		
F	3.40	3.60		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
W	7.90	8.30		

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